











SBOS583B - DECEMBER 2011 - REVISED DECEMBER 2016

TMP709

TMP709 Resistor-Programmable Temperature Switch in SOT Package

Features

- Threshold Accuracy:
 - ±0.5°C Typical
 - ±3°C Maximum (60°C to 100°C)
- Temperature Threshold Set By 1% External
- Low Quiescent Current: 40 µA Typical
- Open-Drain, Active-Low Output Stage
- Pin-Selectable 2°C or 10°C Hysteresis
- Reset Operation Specified at $V_{CC} = 0.8 \text{ V}$
- Supply Range: 2.7 V to 5.5 V
- Package: 5-Pin SOT-23

Applications

- Computers (Laptops and Desktops)
- Servers
- Industrial and Medical Equipment
- Storage Area Networks
- Automotive

3 Description

TMP709 is a fully-integrated, programmable temperature switch with a temperature threshold that is set by just one external resistor within the entire operating range. The TMP709 provides an open-drain, active-low output and has a 2.7-V to 5.5-V supply-voltage range.

The temperature threshold accuracy is typically ±0.5°C, with a maximum of ±3°C (60°C to 100°C). The quiescent current consumption is typically 40 µA. Hysteresis is pin-selectable to 2°C or 10°C.

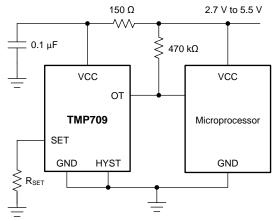
The TMP709 is available in a 5-pin, SOT-23 package.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)	
TMP709	SOT-23 (5)	2.90 mm x 1.60 mm	

(1) For all available packages, see the package option addendum at the end of the datasheet.

Typical Application



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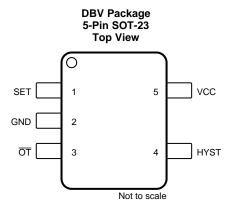
4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

C	hanges from Revision A (February 2012) to Revision B	Page
•	Added Device Information, ESD Ratings, and Recommended Operating Conditions tables, and Detailed Description, Application and Implementation, Power Supply Recommendations, Layout, Device and Documentation Support, and Mechanical, Packaging, and Orderable Information sections	
•	Deleted Package and Ordering Information table; information now available in package option addendum located at the end of this data sheet	
C	hanges from Original (December 2011) to Revision A	Page
•	Updated threshold accuracy feature bullet	1
•	Updated threshold accuracy text in second paragraph of Description section	1
•	Updated temperature error parameter in the Electrical Characteristics	5



5 Pin Configuration and Functions



Pin Functions

Pl	PIN		DESCRIPTION	
NAME	NO.	TYPE	DESCRIPTION	
GND	2	Analog power	nalog power Device ground	
HYST	4	Digital input	Digital input Hysteresis selection. For 10°C, HYST = VCC; for 2°C, HYST = GND.	
ŌT	3	Digital output	output Open-drain, active low output	
SET	1	Analog input	Temperature set point. Connect an external 1% resistor between SET and GND.	
VCC	5	Analog power	Power-supply voltage (2.7 V to 5.5 V)	



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT	
	Supply, VCC	-0.3	6		
Voltage	Input, SET and HYST	-0.3	$V_{CC} + 0.3$	V	
	Output, OT	-0.3	6		
Current	Input		20	mA	
	Output		20		
	Operating, T _A	-40	125		
Temperature	Junction, T _J		150	°C	
	Storatge, T _{stg}	-65	150		

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±4000	
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±1000	V
		Machine model (MM)	±200	

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
V_{CC}	Supply voltage	2.7	5.5	V
T _A	Operating temperature	0	125	°C

6.4 Thermal Information

		TMP709	
	THERMAL METRIC ⁽¹⁾	DBV (SOT-23)	UNIT
		5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	217.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	86.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	44.6	°C/W
ΨЈТ	Junction-to-top characterization parameter	4.4	°C/W
ΨЈВ	Junction-to-board characterization parameter	43.8	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

 For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.5 Electrical Characteristics

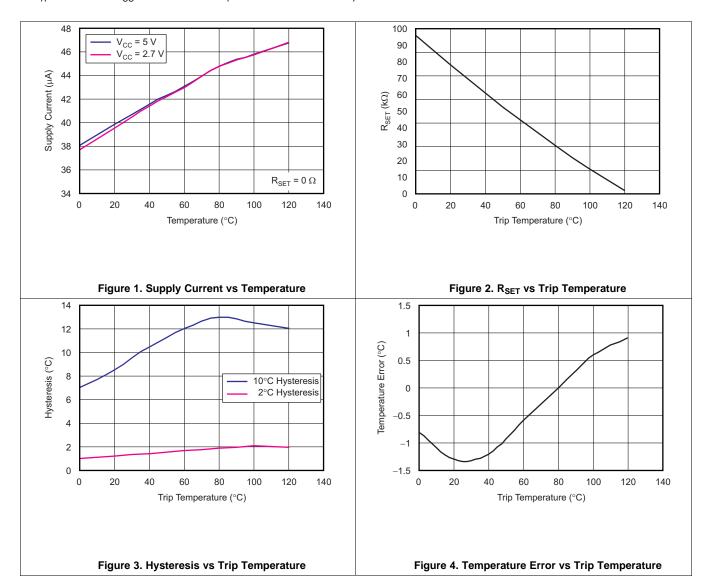
at T_A = 0°C to 125°C and V_{CC} = 2.7 V to 5.5 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER S	UPPLY	·				
	Cumply ourrant	V _{CC} = 5 V		40	55	μΑ
Icc	Supply current	V _{CC} = 2.7 V		40	55	μA
TEMPERA	TURE		·			
T _E	Temperature error	T _A = 60°C to 100°C		±0.5	±3	°C
DIGITAL I	NPUT (HYST)					
V _{IH}	High-level input voltage		$0.7 \times V_{CC}$			V
V _{IL}	Low-level input voltage				0.3 × V _{CC}	V
C _{IN}	Input capacitance			10		pF
ANALOG	INPUT (SET)					
V _{IN}	Input voltage range		0		V_{CC}	V
I _{lkg_in}	Input leakage current			1		μΑ
DIGITAL (OPEN-DRAIN OUTPUT (OT)					
I _(OT_SINK)	Output sink current	V _{OT} = 0.3 V	5	12		mA
I _{lkg(OT)}	Output leakage current	$V_{OT} = V_{CC}$		1		μΑ



6.6 Typical Characteristics

at $T_A = 25$ °C and $V_{CC} = 2.7$ V to 5.5 V (unless otherwise noted)





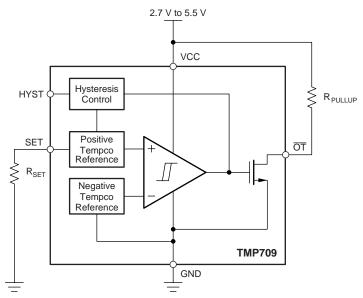
7 Detailed Description

7.1 Overview

The TMP709 is a fully-integrated, resistor-programmable temperature switch that incorporates two temperaturedependent voltage references and one comparator. One voltage reference exhibits a positive temperature coefficient (tempco), and the other voltage reference exhibits a negative tempco. The temperature at which both voltage references are equal determines the temperature trip point.

The Functional Block Diagram shows the comparator, the NFET open-drain device connected to the $\overline{\text{OT}}$ pin, the positive tempco reference using the external R_{SET} resistor, the negative tempco reference, and the hysteresis control. The voltage of the positive tempco reference is controlled by external resistor R_{SET}.

7.2 Functional Block Diagram



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7.3 Feature Description

7.3.1 Temperature Switch

The TMP709 temperature threshold is programmable from 0°C to 125°C and is set by an external 1% resistor from the SET pin to the GND pin. The TMP709 has an open-drain, active-low output structure that easily interfaces with a microprocessor.

The TMP709 reaches the temperature trip point when the voltage from the positive tempco reference exceeds the voltage from the negative tempco reference. This difference causes the output of the comparator to switch from logic 0 to logic 1. The comparator output drives the gate of the NFET open-drain device, and pulls the voltage on the \overline{OT} pin from logic 1 to logic 0 under these conditions; in other words, the output *trips*. Furthermore, the logic 1 output from the comparator causes the hysteresis control to increase the voltage of the positive tempco reference by an amount set by the logic setting on the HYST pin (10°C for logic 1 on the HYST pin; 2°C for logic 0 on the HYST pin). Increase the voltage of the positive tempco reference after the TMP709 trips to stop the TMP709 from untripping (voltage on the \overline{OT} pin changing from logic 0 to logic 1) until the local temperature reduces by the amount set by the HYST pin. After the local temperature reduces, and the voltage from the positive tempco reference is less than the voltage from the negative tempco reference, the output of the comparator switches from logic 1 to logic 0. This condition causes the voltage on the \overline{OT} pin to change from logic 0 to logic 1 (device untrips).

7.3.2 Hysteresis Input

The HYST pin is a digital input that allows the input hysteresis to be set at either 10°C (when HYST = VCC) or 2°C (when HYST = GND). The hysteresis function keeps the \overline{OT} pin from oscillating when the temperature is near the threshold. Thus, always connect the HYST pin to either VCC or GND. Other input voltages on this pin can cause abnormal supply currents or a device malfunction.

7.3.3 Set-Point Resistor (R_{SET})

Set the temperature threshold by connecting R_{SET} from the SET pin to GND. The value of R_{SET} is determined using either Figure 2 or Equation 1:

 $R_{SET}(k\Omega) = 0.0012T^2 - 0.9308T + 96.147$

where

• T = temperature threshold in degrees Celsius.

(1)

7.4 Device Functional Modes

The TMP709 device has a single functional mode. Normal operation for the TMP709 device occurs when the power-supply voltage applied across the VCC and GND pins is within the specified operating range of 2.7 V to 5.5 V.



8 Applications and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TMP709 device is simple to configure. The only external components that the device requires are a bypass capacitor and pullup resistor. Power-supply bypassing is strongly recommended. Use a 0.1- μ F capacitor placed as close as possible to the VCC supply pin. To minimize the internal power dissipation of the TMP709 family of devices, use a pullup resistor value greater than 10 k Ω from the \overline{OT} pin to the VCC pin. See the *Hysteresis Input* section for hysteresis configuration, and the *Set-Point Resistor* (R_{SET}) section for configuring the temperature threshold.

8.2 Typical Application

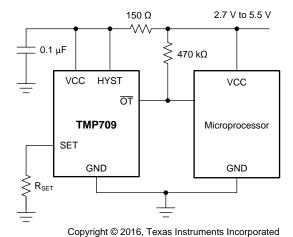


Figure 5. Overtemperature Protection for a 60°C Trip Point

8.2.1 Design Requirements

For this design example, a 2.7-V to 5.5-V power supply, 60°C trip point, and 10°C hysteresis are used.



Typical Application (continued)

8.2.2 Detailed Design Procedure

Connect the HYST pin to VCC for 10°C hysteresis. For a 60°C temperature threshold, see the Set-Point Resistor (R_{SET}) section to compute an ideal R_{SET} resistor value of 44.619 k Ω . Select the closest standard value resistor available; in this case, 44.2 k Ω . Use a 10-k Ω pullup resistor from the $\overline{\text{OT}}$ pin to the VCC pin. To minimize power, a larger-value pullup resistor can be used, but must not exceed 470 kΩ. Place a 0.1-μF bypass capacitor close to the TMP709 device in order to reduce noise coupled from the power supply.

8.2.3 Application Curves

Figure 6 shows an example of the hysteresis feature. The HYST pin is connected to VCC, so the TMP709 device is configured for 10°C of hysteresis. The device is configured for a 60°C trip temperature by the R_{SFT} resistor value; therefore, the OT output asserts low when the 60°C threshold is exceeded. The OT output remains asserted low until the sensor reaches 50°C.

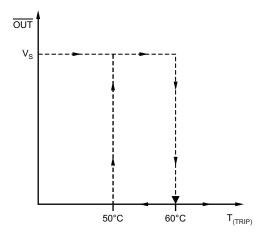


Figure 6. TMP709 Hysteresis Function



9 Power Supply Recommendations

The TMP709 low supply current and supply range allow this device to be powered from many sources. Any significant noise on the VCC pin can result in a trip-point error. Minimize this noise by low-pass filtering the device supply (V_{CC}) using a 150- Ω resistor and a 0.1- μ F capacitor.

10 Layout

10.1 Layout Guidelines

The TMP709 is extremely simple to lay out. Figure 7 shows the recommended board layout.

10.2 Layout Example

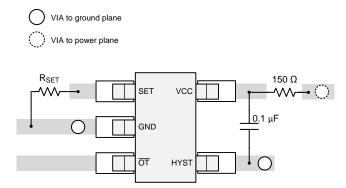


Figure 7. Recommended Layout

10.3 Thermal Considerations

The TMP709 quiescent current is typically 40 μ A. The device dissipates negligible power when the output drives a high-impedance load. Thus, the die temperature is the same as the package temperature. In order to maintain accurate temperature monitoring, provide a good thermal contact between the TMP709 package and the device being monitored. The rise in die temperature as a result of self-heating is given by Equation 2:

$$\Delta T_J = P_{DISS} \times \theta_{JA}$$

where

- P_{DISS} = power dissipated by the device.
- θ_{JA} = package thermal resistance. Typical thermal resistance for SOT-23 package is 217.9°C/W. (2)

To limit the effects of self-heating, keep the output current at a minimum level.

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11 Device and Documentation Support

11.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

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11.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TMP709AIDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	SBJ
TMP709AIDBVR.Z	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SBJ
TMP709AIDBVRG4.Z	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SBJ

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF TMP709:

Automotive: TMP709-Q1

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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NOTE: Qualified	Version	Definitions
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• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	-
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TMP709AIDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TMP709AIDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TMP709AIDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TMP709AIDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0



SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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